Unstable ux ow due to heated electrons in Y-Ba-Cu-O lm s

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A ux instability occurs in superconductors at low temperatures, where ee scattering is more rapid than ep, whereby the dissipation signi cantly elevates the electronic temperature while maintaining a thermal-like distribution function. The reduction in condensate and rise in resistivity produce a non-monotonic current-voltage response. In contrast to the Larkin-O vchinnikov instability where the vortex shrinks, in this scenario the vortex expands and the quasiparticle population rises. Measurements in $Y_1Ba_2Cu_3O_7$ agree quantitatively with the distinct predictions of this mechanism.

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In a type II superconductor, magnetic elds between the lower critical value H_{c1} and upper critical eld H_{c2} introduce ux vortices containing a quantum of ux $_{\circ}$ = h=2e. Here we have superconducting Im s in a perpendicular applied ux density B, with a transport electric current density j in the plane of the Im, which exerts a Lorentz driving force F_L = j $_{\circ}$. The vortex m otion generates an electric eld E = vB and is opposed by a viscous drag v (is the coe cient of viscosity and v the vortex velocity), so that in steady state j $_{\circ}$ = v and the response is 0 hm ic. Larkin and 0 vchinnikov (1986) have shown that a dirty superconductor at low tem peratures has a free- ux- ow resistivity related to the norm alstate value _n by [1]

$$f = n' 0:9B = H_{c2}(T):$$
 (1)

Approximately the same result, without the precise 0.9 prefactor, can be obtained by considering the 0 hm ic dissipation in the core and temporal changes in the order parameter leading to irreversible entropy transfer [2]; the result is also valid for d-wave superconductors that are not superclean [3]. Eq. 1 is equivalent to $_{0}H_{c2}=_{n}$. At low levels of j and E, in the assumed dirty limit $1 = E_{\rm F} = kT_{\rm c}$ (l is the mean free path and $E_{\rm F}$ is the Ferm ienergy), is a constant that is proportional to the size

² (where is the coherence length) of the vortex [4]. (The Halle ect and transverse component of E are negligible for this discussion, as is vortex pinning because of the large driving forces [5].)

At high electric elds and dissipation levels su cient to alter the electronic distribution function and/or the electronic tem perature, j(E) become some some and can develop an unstable region (dj=dE < 0) above some critical vortex velocity v. For the regime near T_c , such an instability has been predicted by Larkin and Ovchinnikov (LO) [6], and has been experimentally well established [7, 8, 9, 10]. At high tem peratures, the electron-phonon (ep) scattering time $_{ep}$ can be shorter than the electron-electron (ee) scattering time $_{ep}$ preventing internal equi-

libration of the electronic system and producing a peculiar non-therm all distribution function. Since the order is especially sensitive to the distribution param eter function when close to ${\rm T_c}$, even moderate values of E can su ciently distort (via the E liashberg m echanism [11]) causing a shrinkage of the vortex core and a rem oval of quasiparticles from its vicinity. This is the gist of the LO behavior [6, 7]. As LO them selves emphasize, the e ect is most favorable close to T_c for superconductors with a fullgap and, as shown by Bezuglyjand Shklovskij [12], is dominant for $B < B_T$ (with B_T 0:1 T for our low-T regime). One of the predictions of the standard LO e ect is a v that is B independent. This has been con $m ed in Y_1 Ba_2 Cu_3 O_7$ in the high-T range [9, 10].

This work investigates the opposite regime of T T_{c} and $B > B_T$, where is not sensitive to sm all changes in the distribution function. Furtherm ore because $_{
m ee}$ < ep as T ! 0, the distribution function remains therm al like and the electronic system su ers mainly a temperature shift with respect to the lattice [6, 12, 13, 14]. Then instead of the standard LO picture described earlier, we consider a more transparent scenario where the main effect of the dissipation is to raise the electronic temperature, create additional quasiparticles, and dim inish The vortex expands rather than shrinks, and the viscous drag is reduced because of a softening of gradients of the vortex pro le rather than a rem oval of quasiparticles. This sequence of events is almost opposite to the standard LO picture and represents a new type of unstable regim e prevalent at T T_c. All experim entalm easurables can be calculated without ambiguity, and the predicted eld dependencies and full j(E) curves t the experim ental results without any adjustable param eters.

P reviously som e deviations from LO behavior at interm ediate tem peratures | such as a B -dependent v | were treated through modi cations to the LO e ect, such as an intervortex spacing 1 that exceeds the energy-relaxation length 1 [15] or by inclusion of therm all e ects [12, 13]. Those treatments do not apply to the present T T_c regim e where 1 D_{ep} 100{1000 nm is larger than Here we take a \bottom -up" approach and start from the T 0 lim it: The total input power jE travels from electrons to lattice and from there to the bath, so that $T_0 < T_p < T^0$, where T_0 and T_p are the bath and phonon temperatures, and T^0 is the raised non-equilibrium electronic temperature. M acroscopic heating, represented by T_p $T_0 = R_{th}$ jE, is < 5% of the total increase T^0-T_0 for the worst case dissipation so that T_p T_0 (Here R_{th} 1 nK cm³/W is the total therm al resistance between the

In and the bath; see experimental section. It will be seen later that the speci c-heat integral heavily weights the higher temperatures, so that $T_p - T_0$ is quite negligible.). The energy relaxation between electrons and lattice occurs by inelastic ep scattering, and is characterized by an elective time $<_{ep}>$. The principle contributions to $_n$ come from in purities and phonons. Since the phonon temperature remains near the bath, $_n$'s value will not change as the non-equilibrium T⁰ rises. Thus putting $_n(T_0)$ and H $_{c2}$ (T⁰) (since H $_{c2}$ does depend on T⁰) into previous equations gives the j(E) response in term s of T⁰:

$$j = v (T^{0}) = _{0} = E H_{c2} (T^{0}) = _{n} (T_{0})B$$
: (2)

O ne now has the ingredients for calculating the critical eld dependencies in a few steps. The j(E) function of Eq.2 is non-monotonic since E is multiplied by H_{c2} (T⁰) (or (T⁰)) which drops rapidly to zero as T⁰! T_c with increasing dissipation. The instability occurs at dj=dE = 0, which happens at a certain value T⁰=T where H_{c2} (T⁰) (or (T⁰)) drops su ciently rapidly. T⁰ depends explicitly only on the power density jE = $v^2B = _0$ and on quantities that depend on T⁰ itself (, speci cheat, etc.). Hence at the instability, j E = v^2 (T)B = $_0$ = constant, which gives the critical-parameter eld dependencies:

$$v / 1 = B; E / B; j / 1 = B; and / B (3)$$

using $E = v B_{p,j} = v$ (T) = 0, and = E / j. This gives v / 1 = B in a natural way, consistent with our measurements in this regime and in contrast to the B - independent v of the pure LO e ect near T_c .

To derive the complete j(E) response and absolute values of critical parameters we calculate T⁰ and insert it into Eq.2. We take H_{c2}(0)=120 T [16] with the W HH function [17] for interpolation between this H_{c2}(0)=120 and H_{c2}(T_c)=0 (There is some theoretical controversy regarding the exact form of H_{c2}(T); however, empirically, direct measurements [16] of H_{c2}(T), within their uncertainity, seem not to depart drastically from the W HH function, and the exact functional shape does not crucially a ect our conclusions.). The dissipation raises the

electronic energy by jE , which is related to T^0 by

$$jE = \frac{E^{2}H_{c2}(T^{0})}{n(T_{0})B} = \frac{Z^{0}}{c(T)dT} = C(T)dT = C(T)d$$

where c(T) is the electronic speci c heat. To calculate c(T), $Y_1Ba_2Cu_3O_7$ is modeled as a layered dwave superconductor: ${}_{\mathbb{R}}(T) = {}_0(T)[k_x^2 \quad k_y^2]=k^2$

 $_0$ (T) cos(2), taking the BCS tem perature dependence for $_0$ (T) and $_0$ (0)=19 meV from tunpeling and infrared m easurements [18]. Then c(T)=0f $_k$ E $_k$ f $_k$ g=0T, where f_k = [exp (E $_k = k_B T$) + 1] 1 is the Ferm i-D irac distribution, E $_k$ = $\binom{2}{k} + \frac{2}{k}$, $_k$ = $_k$, and =0.2 eV is the chemical potential [19]. W ith the replacement of $_k$ by d N (0) d =2 (where N (0) is the normal density of states at) this c(T) is now inserted into Eq.4, which is integrated num erically to obtain T 0 and thence j(E) from Eq.2.

The numerical results of the above calculation are shown in Fig. 1. The j(E) curves of panel (a) have an in nite slope at the instability (j, E), indicated by arrows, and then exhibit negative slope. This negative sloped portion is experimentally forbidden in a current biased measurement and instead will be manifested as a vertical jump in E. The electronic temperature T⁰ rises from the bath value T₀ to T at the instability. Panel (b) shows the computed T , which is independent of B as expected but has a slight dependence on the bath tem – perature T₀.

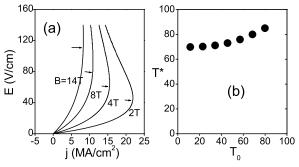


FIG.1: Numerical results obtained from solving Eq.4, as described in the text. (a) Theoretical j(E) curves, at T_0 = 0K. The onset of negative slope, indicated by arrows, marks the instabilities. (b) The critical temperature T for di erent initial temperatures T_0 ; T is independent of B and .

In order to conveniently scale the experim ental curves, the exact num erical j(E) function derived above | and plotted in Fig. 1 | can be cast into a mathematically moremanageable form by noting that the R H S.ofEq.4 can be approximated [?] by jE $(T^0)n_q(T^0)$ $(T_p)n_q(T_p)$ $(T^0)n_q(T^0)$. and n_q are connected through the statistical equations of the previous paragraph. Num erically computing the num ber of quasiparticles excited above the gap (taking the anisotropic d-wave

gap together with a BCS tem perature dependence as discussed above) we obtain the following d-wave generalization of the n_q relationship [?]: $(=_0)^2 = f(n_q=n)$, where n = 2:7 10^{21} cm⁻³ is the carrier concentration and f(x) ' 1 0:4386x $1539\hat{x} + 40381x^3$ $345217x^4$ (despite the appearance of successively increasing coe cients in f(x), the terms rapidly converge because $x = n_q/n$ $k_B T = E_F$ 0.01). Combining this with the earlier jE $(T^0)n_q(T^0)$, $= j_{-0}=v = j_{-0}B = E$, H_{c2} $_{0}=$ n, and / , we get a convenient closed

form for the non-linear $j \in J$ characteristic:

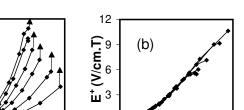
$$j \qquad \frac{H_{c2}(\Gamma_0)}{B_n(\Gamma_0)} E^{p} \overline{f(x)}$$
(5)

instability peak. We now turn to the experimental details and results.

The samples are c-axis oriented epitaxial lms of $Y_1Ba_2Cu_3O_7$ on (100) LaA D_3 substrates with T_c 's around 90K and of thickness t 90 nm . E lectron-beam lithography was used to pattern bridges of widths w 30{200 m. Altogether ten 2{20 m and lengths 1 sam ples were studied at 12 tem peratures (1.6, 2.2, 6, 7, 8, 10, 20, 27, 35, 42, 50, 80 K) and at 13 ux densities (01,02,05,1,15,2,10,11,13,135,138,14,158T). The electrical transport measurements were made with a pulsed constant current source, pream pli er circuitry, and a digital storage oscilloscope. The pulse rise times are about 100 nsw ith a duty cycle of about 1 ppm, which for the narrowest bridges result in e ective therm al resistances of order 1 nK cm^3/W . Note that the j values in the experiment are an order of magnitude lower than the depairing current density [20] and the applied ux densities exceed the self eld of the current by at least two orders of m agnitude. Further details about the experim ental techniques are discussed elsewhere [21].

Fig. 2(a) shows a typical set of experimental j(E) curves. The last stable datapoint (j, E) of each curve is at the tail of each arrow. The slightest further increase of j > j causes a drastic vertical jum p in E as shown by the arrows (the voltage pulse jumps o the scale of the oscilloscope up to the compliance lim it of the current source). The jum ps show only a sm all hysteresis < 3% of j. (A s expected for a current-biased m easurem ent, the break occurs slightly before the slope has become quite vertical [12].) Fig. 2 (b) shows the same data plotted as the R.H.S. of Eq. 5 vs j \dot{z}_0 , the excess current density over the depinning value. The data scale well and tend toward hom ogeneous linearity. Note that the collapse in plies an excellent proportionality between and B over the entire range.

Fig.3 shows experimentally measured B dependencies of v and for $T_0 = 1.6$ K, demonstrating excellent agreement with Eq.3 (the other dependencies E / B and



0

3

6

9

0

-3

 $j (MA/cm^2) \qquad j - j_{c0} (MA/cm^2)$ FIG. 2: Experimental current-voltage characteristics. (a) Raw values of E versus j at T = 20K and applied B values of (from lowest to highest curve) 3, 5, 8, 11, 13.8, and 15.8 T. The last symbol on each curve is right at the instability. Slightest further increase of j (entering the forbidden negative-sloped portion of the theoretical curves of Fig. 1) causes E to make discontinous vertical jumps (arrows). (b) The same data plotted as E⁺ = (E = B) $\frac{1}{f} (0.0245E^2 = E^2)$ (as per Eq.5) versus j j_{c0}, where the critical depinning current density j_{c0} is de ned at E⁺ = 1 V/cm T (the scaling is not a ected by the choice of criterion).

120

(**u**)⁹⁰/₆₀

ш₃₀

0

0

(a)

5

10

15

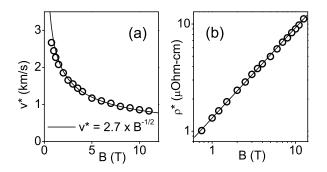


FIG. 3: Variation of critical parameters with ux density. The measurements were made at T = 1.6 K. (a) The critical velocity shows a v / 1 = B trend (solid line is a 1 = B t). (b) The critical resistivity is proportional to the ux density (straight line is a guide to the eye).

 $p = p_{p}$ follow from / B and v / 1 = B). The v / 1 = B dependence was found to be ubiquitous for all of our low -T m easurements in ten samples (spanning 1.6 K T 50 K and 0.5 T B 15.8 T) and has also been seen by X iao et al. [10] at intermediate tem - peratures (at the lower end of their T 60 {90 K range of study). Note that the excellent linearity between between and B demonstrates the independence of on B in this regime; then the resistivity is simply proportional to the num ber of vortices and hence B.

The nal step in the analysis is to extract from the data. Inverting Eq. 4 evaluated at the instability (i.e., at $T^0 = T$), we get $\frac{\frac{n}{(T_0)B}}{\frac{R}{H_{c2}(T_0)E^{-2}}} R_{T_0} c(T) dT$; the T (T_0) function comes from the model itself (Fig. 1 (b)). calculated in this way is shown by the circles in

calculated in this way is shown by the circles in Fig. 4. If the data are analyzed in the LO frame-

work ($D [14 (3)]^{=2}B^{2}=(E^{2}))$ a markedly longer is obtained shown by the squares. For compar-

is obtailed shown by the squares. For comparison the arrow shows the theoretical T! 0 limiting value estimated from spontaneous emission of phonons. (Emission of non-equilibrium phonons dominates episcattering by thermal phonons below a cross-over tem – perature $T_x = m v_F c_s = k_B$ 43 K producing an essentially T-independent scattering rate (since kT E_F) of $e_p = (3 M c_s^{-2}) = (2C^2m k_F)$ 8:4 10^{11} , where C 6 10^{-13} ergs is the coupling between electron energy and crystal dilation, $c_s = 4 \text{ km/s}$ is the sound velocity, and $M = 6 \text{ g/cm}^3$ is the mass density [22]; for further discussion see, for example, K ittel [23].)

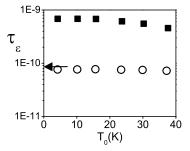


FIG. 4: The energy relaxation time extracted from the measured data using the present low-tem perature instability model (circles) and from LO theory (squares). The leftward arrow represents the theoretical T ! 0 limiting value of $_{\rm ep}$ from phonon em ission (please see text).

In conclusion, we investigated the low-temperature regime of ux motion driven far beyond free ux OW. and observed an instability under all conditions of elds, and tem peratures from $T_c/2$ down to essentially T 0. The nature of this low-tem perature instability seems to be well described by a model where the electron gas is heated above the phonon tem perature leading to the generation of quasiparticles and loss in viscosity as the vortex is reduced. This scenario is di ercore expands and ent from the standard LO picture (dom inant mainly near T_c) where the vortex shrinks and quasiparticles leave its vicinity. Because the present e ect prevails even at tem peratures wellbelow T_c (where most superconductive devices operate) it becom es an important consideration in the design of applications where the superconductor operates in the dissipative regim e [24], since the instability triggers an abrupt rise in dissipation at j values much below the depairing current density. Detailed predictions of the model, including eld dependencies of critical param eters and shapes of j (E) curves were experim entally veried, and the e ect provides an estimate of the T! 0 time scale for energy exchange between quasiparticles and phonons.

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- A.I.Larkin and Yu.N.Ovchinnikov, in Nonequilibrium Superconductivity, D.N.Langenberg and A.I.Larkin, eds. (Elsevier, Am sterdam, 1986), Ch.11.
- [2] J. Bardeen and M. J. Stephen, Phys. Rev. 140, A 1197 (1965); M. Tinkham, Phys. Rev. Lett. 13, 804 (1964); and J.R. Clem, Phys. Rev. Lett. 20, 735 (1968).
- [3] N.B.Kopnin and G.E.Volovik, Phys. Rev. Lett. 79, 1377 (1997).
- [4] A physically intuitive discussion can be found in M ichael. T inkham, Introduction to Superconductivity, 2nd E dition (M cG raw H ill, N ew York, 1996).
- [5] M.N.Kunchur, D.K.Christen, and J.M.Phillips, Phys. Rev.Lett. 70, 998 (1993).
- [6] A. I. Larkin and Yu. N. Ovchinnikov, Zh. Eksp. Teor. Fiz. 68, 1915 (1975) [Sov. Phys. JETP 41, 960 (1976)].
- [7] W. Klein, R. P. Huebener, S. Gauss, and J. Parisi, J. Low Temp. Phys. 61, 413 (1985).
- [8] L.E.M usienko, I.M. Dm itrenko, and V.G. Volotskaya, Pis'm a Zh.Eksp.Teor.Fiz. 31, 603 (1980) [JETP Lett. 31, 567 (1980)]; and A.V.Sam oilov et al., Phys.Rev. Lett. 75, 4118 (1995).
- [9] S.G.D oettinger et al, Phys.Rev.Lett. 73, 1691 (1994).
- [10] Z.L.X iao et al, Phys.Rev.B 53, 15265 (1996).
- [11] G.M. Eliashberg, JETP Lett. 11, 114 (1970) [Sov. Phys. JETP 34, 668 (1972)]; and B.I. Ivlev, S.G. Lisitsyn, and G.M. Eliashberg, J.Low Tem p. Phys. 10, 449 (1973).
- [12] A.I.Bezuglyjand V.A.Shklovskij, Physica C 202,234 (1992).
- [13] A.I.Bezuglyj, Physica C 323, 122 (1999).
- [14] V.G.Voltskaya, et al., Sov.J.Low Tem p.Phys. 18, 683 (1993).
- [15] S.G.Doettinger et al., Physica C 251, 285 (1995).
- [16] H.Nakagawa, N.M iura, and Y.Enomoto, J.Phys.: Condens. M atter 10, 11571 (1998).
- [17] N. R. W ertham er, E. Helfand, and P. C. Hohenberg, Phys. Rev. 147, 295 (1966).
- [18] W .Lanping et al, Phys. Rev. B 40, 10954 (1989); and R.T.Collins et al, Phys. Rev. Lett. 59, 704 (1987).
- [19] C. Poole, H. A. Farach, and R. J. Creswick, Superconductivity (A cadem ic Press, San Diego, 1995).
- [20] M.N.Kunchur, D.K.Christen, C.E.K labunde, and J. M.Phillips, Phys. Rev. Lett. 72, 752 (1994).
- [21] M.N.Kunchur, Mod. Phys. Lett. B. 9, 399 (1995).
- [22] N IST W ebH T S D atabase, http://www.ceramics.nist.gov/srd/hts/htsquery.htm
- [23] C. K ittel, Introduction to Solid State Physics, seventh edition, (John W iley and Sons, New York, 1996), appendix J.
- [24] The author has an ongoing project (funded by Lockheed M artin, Inc.) to explore the high-dissipation regime for the operation of pulsed superconductive m agnets for fusion energy devices.